Supplementary Information

Ultra-thin flexible paper of BNNT-CNF/ZnO ternary nanostructure for enhanced solidstate supercapacitor and piezoelectric response

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S1. Preparation of the ZnO nanoparticles

Typically, Zinc acetate (2.6 wt%) and KOH (0.26 wt%) were each dispersed in methanol at 60 °C. The molar ratio of zinc acetate and KOH was fixed as 2:1. The KOH solution was added dropwise into the Zn (CH₃COO)₂.2H₂O solution under constant stirring for 1.5 h at 60 °C. Consequently, the solution mixture was permitted to cool slowly at ambient conditions, than the mixture was cleaned by using centrifugations (7000 rpm, 10 min) with the ethanol and deionized (DI) water. The final white precipitate was obtained and dried in a oven for overnight and the product was labelled as ZnO NP.



Figure S2 (a-c). High-resolution O 1s x-ray photoelectron spectroscopy for the (a) pristine BNNT,(b) BNNT-ZnO hybrid and (c) BNNT-CNF/ZnO ternary nanostructure.



Figure S3 (a-d). Cyclic Voltammetry (CV) curves for the **(a)** pristine BNNT, **(b)** pristine ZnO, **(c)** BNNT-CNF hybrid and **(d)** BNNT-ZnO hybrid under various scan rates ranging from 10 mV/s to 60 mV/s in three electrode measurements.



Figure S4 (a-d). Galvanostatic charging-discharging curves for the **(a)** pristine BNNT, **(b)** pristine ZnO, **(c)** BNNT-CNF hybrid and **(d)** BNNT-ZnO hybrid under various scan rates ranging from 10 mV/s to 60 mV/s in three electrode measurements.



Figure S5. Cycling stability test under 5000 GCD cycles for the pristine BNNT, pristine ZnO, BNNT-CNF, BNNT-ZnO hybrid and BNNT-CNF/ZnO ternary nanostructure under 20 A/g of current density in a three electrode measurements.



Figure S6. CV curves of BNNT-ZnO hybrid under various scan rates ranging from 10 mV/s to 50 mV/s in two electrode measurements.



Figure S7. CV curves of BNNT-CNF hybrid under various scan rates ranging from 10 mV/s to 50 mV/s in two electrode measurements.



Figure S8. CV curves of pristine ZnO under various scan rates ranging from 10 mV/s to 50 mV/s in two electrode measurements.



Figure S9. CV curves of pristine BNNT under various scan rates ranging from 10 mV/s to 50 mV/s in two electrode measurements.



Figure S10. GCD curves of BNNT-ZnO hybrid under various current densities ranging from 1 A/g to 10 A/g in two electrode measurements.



Figure S11. GCD curves of BNNT-CNF hybrid under various current densities ranging from 1 A/g to 10 A/g in two electrode measurements.



Figure S12. GCD curves of pristine ZnO under various current densities ranging from 1 A/g to 10 A/g in two electrode measurements.



Figure S13. GCD curves of pristine BNNT under various current densities ranging from 1 A/g to 10 A/g in two electrode measurements.



Figure S14. BNNT-CNF/ZnO ternary nanostructure paper performance such as (**a**) FESEM micrographs before cycling stability test, (**b**) after cycling stability (over 5000 cycles), and (**c**) XRD after cycling stability test. (**d**) Photo digital images for the BNNT-CNF/ZnO ternary nanostructure papers at different positions and (**e**) flexible symmetric supercapacitor device picture at different positions.



Figure S15. FESEM micrographs of the (a) BNNT-CNF and (b) BNNT-CNF/ZnO flexible paper.

Table S1. Comparative electrochemical performance of BNNT-CNF/ZnO in the three-electrode

 system with other previously reported materials.

Electrode materials	Electrolyte	Voltage window (V)	Capacitance (F/g) / Current density (A/g)	Ref.
BNNT-CNF/ZnO	3 M KOH	0.1 to 0.6	968 / 1	Present work
Co ₃ O ₄ @CNF	3 М КОН	-0.2 to 0.6	789.9 / 1	1
ZnMn ₂ O ₄ /C	6 M KOH	0 to 1.2	589 / 1	2
ZnO/MnO ₂ nanowires	1 M Na ₂ SO ₄	0 to 0.9	501 / 2	3
ZnMn ₂ O ₄ /carbon	6 M KOH	-1 to -0.3	105 / 0.3	4
ZnO nanocones	1 M KOH	0.1 to 0.6	236 / 1	5
NCA/Co ₃ O ₄	6 M KOH	-0.05 to 0.45	616 / 1.2	6
CuCo ₂ S ₄ /CNT/graphe ne	1 M Na ₂ SO ₄	0 to 0.6	504 / 10 /	7
CPSC-3rGO	0.2 M Na ₂ SO ₄	-0.2 to 0.8	446 / 1	8
CS@ZnO Core-shell	6 M KOH	0 to 0.4	630 / 2	9
Co ₃ O ₄ nanoflakes@SrGO	2 M KOH	-0.2 to 0.5	406 / 1	10
CoMoO ₄ nanoclusters	6.0 M KNO ₃	-0.9 to 0.6	367 / 1.2	11
ZnO-/core like MnO ₂	1 M Na ₂ SO ₄	0-0.8	221 / 0.5	12
Ni-Co selenide	6 M KOH	0 to 0.6	742.4 /1	13
ZnO/MnO ₂	0.5 M Na ₂ SO ₄	0 to 0.8	262 / 0.2	14

Table S2. Comparative electrochemical performance of BNNT-CNF/ZnO in all solid state

 symmetric/Asymmetric supercapacitor devices with other previously reported materials.

Electrode materials	Туре	Electrolyte	Capacitance (F/g) / Current density (A/g)	Capacitance retention (%) / cycles	Ref.
BNNT- CNF/ZnO	Symmetric	PVA-KOH solid gel	300 / 1	96 / 5000	Present work
Co ₃ O ₄ @CNF	Symmetric	PVA-KOH gel	214 / 1.0	94 / 5000	1
NCOs	Symmetric	1.0 M KOH	89 / 0.23	-	15
CNF-RGO	Symmetric	H ₂ SO4-PVA	203 / 0.7	99 / 5000	16
1D-CoSe ₂ nanoarrays	Symmetric	РVА-КОН	152 / 0.5	96.8 / 5000	
ZnO/Co ₃ O ₄ - 450//AC	Asymmetric	1.0 M KOH	153 / 1	-	17
CC@NiC2O4 //CC@NC	Asymmetric	6.0 M KOH	89.7 / 1	86.7 / 20000	18
Co ₃ O ₄ @Ni ₃ S ₂	Asymmetric	3.0 M KOH	126 / 1	83.5 / 5000	19
Co ₃ O ₄ @Ni(OH) 2//AC	Asymmetric	6.0 M KOH	110 / 2.5	86 / 1000	20
3D graphene- MoS ₂ hybrid	Symmetric	KOH/PVA	58.0 / 2	-	21
MoS ₂ -NH ₂ /PANI nanosheets	Symmetric	1 M H ₂ SO ₄	58.6 / 2	96.5 / 10000	22
MoS ₂ /CNS	Symmetric	1 M Na ₂ SO ₄	108 / 1	-	23

MoS ₂ /G nanobelts	Symmetric	1 M Na ₂ SO ₄	278.2 / 0.8	-	24
MoS ₂ /rGO	Symmetric	1 M H ₂ SO ₄	306 / 0.5	-	25
NiS/MoS2@N- rGO	Symmetric	6 M KOH	1028 / 1	94.5 / 50000	26
VSL- MoS2@3D-Ni foam	Symmetric	Na ₂ SO ₄ /PVA	34.1 / 1.3	82.5 / 10000	27
MoS ₂ /rGO	Symmetric	NaOH	323 / 0.2	76.8 / 500	28
SS/MWCNTs/M oTe ₂	Symmetric	PVA-LiClO ₄	68.01 / 0.2	94 / 2000	29
MWCNTs/MoSe	Symmetric	PVA-KOH	27 / 0.4	95 / 1000	30

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